

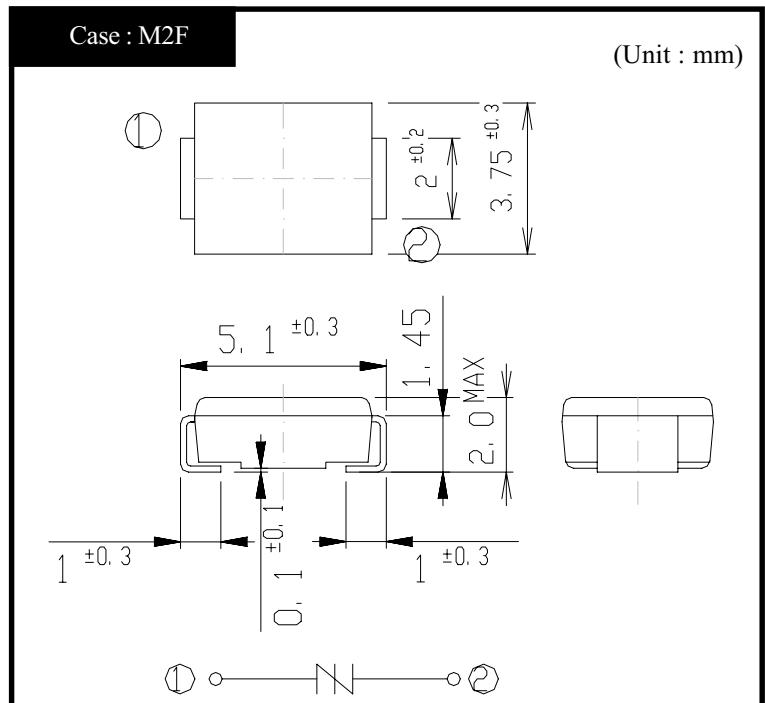
SHINDENGEN

TSS KU Series

SMT

KU10S35N

OUTLINE DIMENSIONS



RATINGS

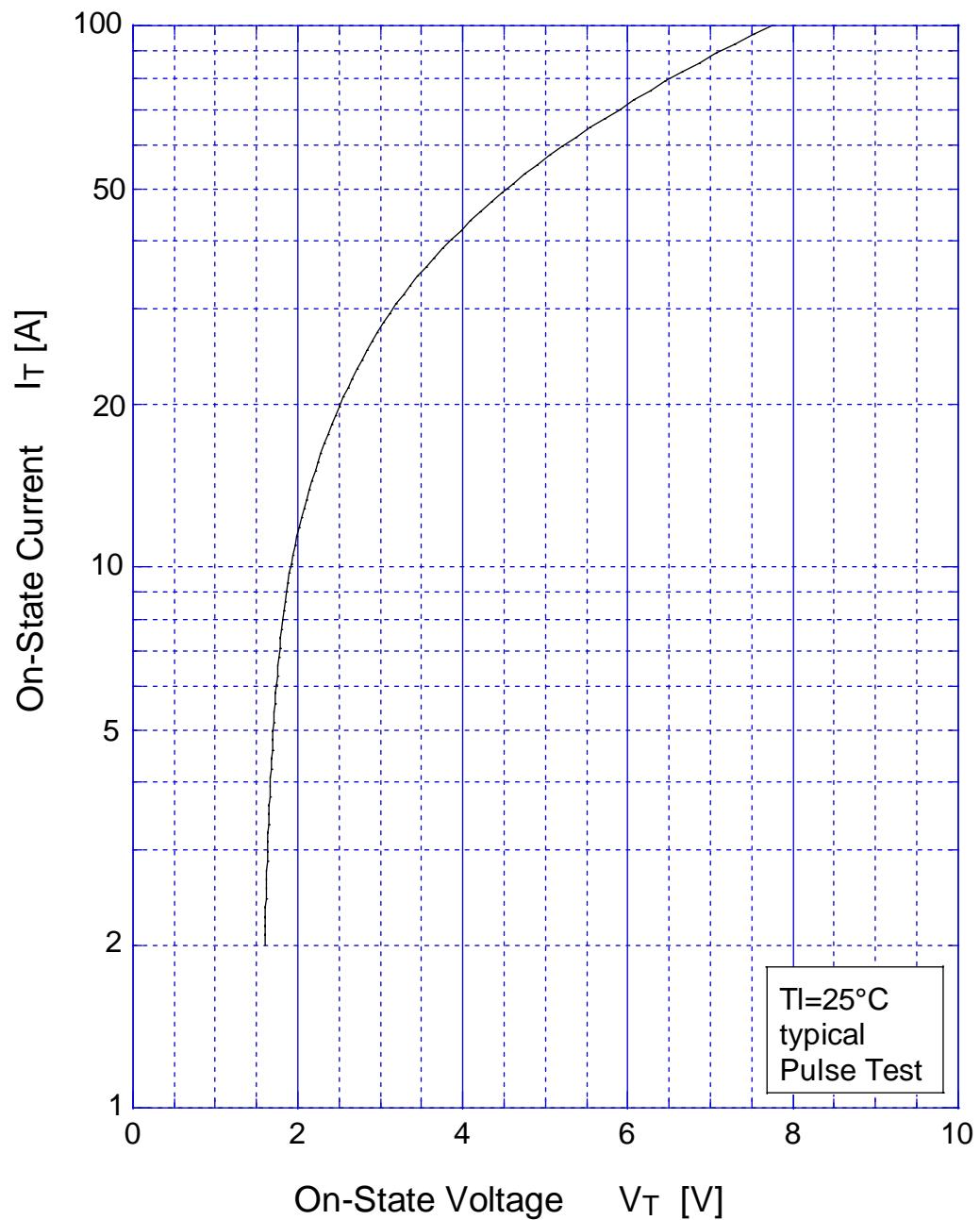
● Absolute Maximum Ratings (Unless otherwise specified, TI=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40~125	°C
Junction Temperature	T _j		125	°C
Maximum Off-State Voltage	V _{DRM}		275	V
Surge On-State Current	I _{TSM}	Pluse-waveform 10/1000 μ s, Non-repetitive	100	A

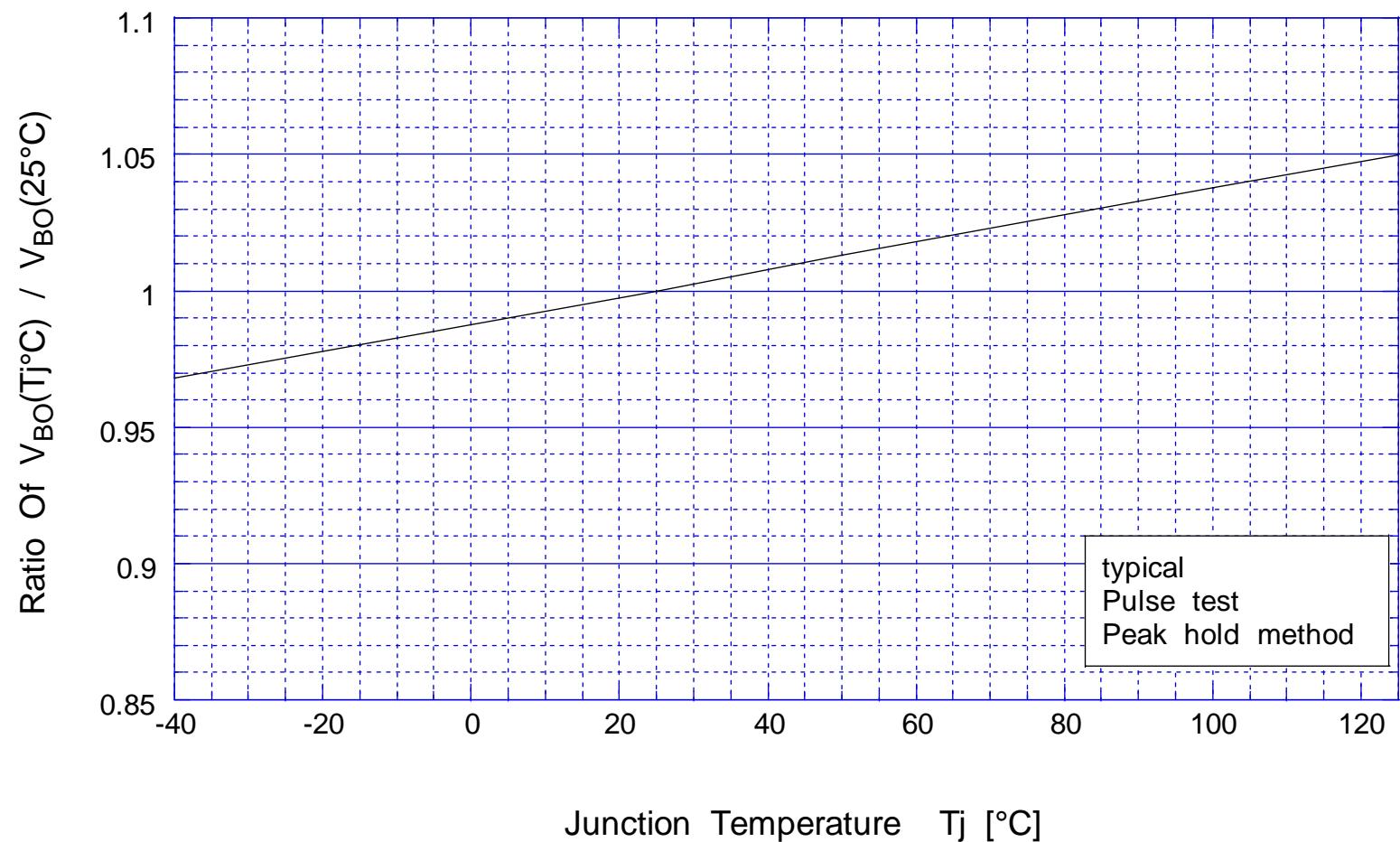
● Electrical Characteristics (Unless otherwise specified, TI=25°C)

Item	Symbol	Conditions	Ratings	Unit
Breakover Voltage	V _{BO}	dv/dt = 8V /ms (Peak hold)	Min 310	V
Off-State Current	I _{DRM}	V _D = V _{DRM}	Max 5	μA
Holding Current	I _H	Pulse measurement	Min 100	mA
On-State Voltage	V _T	I _T = 2A	Max 3	V
Capacitance	C _j	f = 1kHz, V _D = 50V	Max 90	pF
Clamping Voltage	V _{CL}	dv/dt = 100V/ μ s	Max 450	V

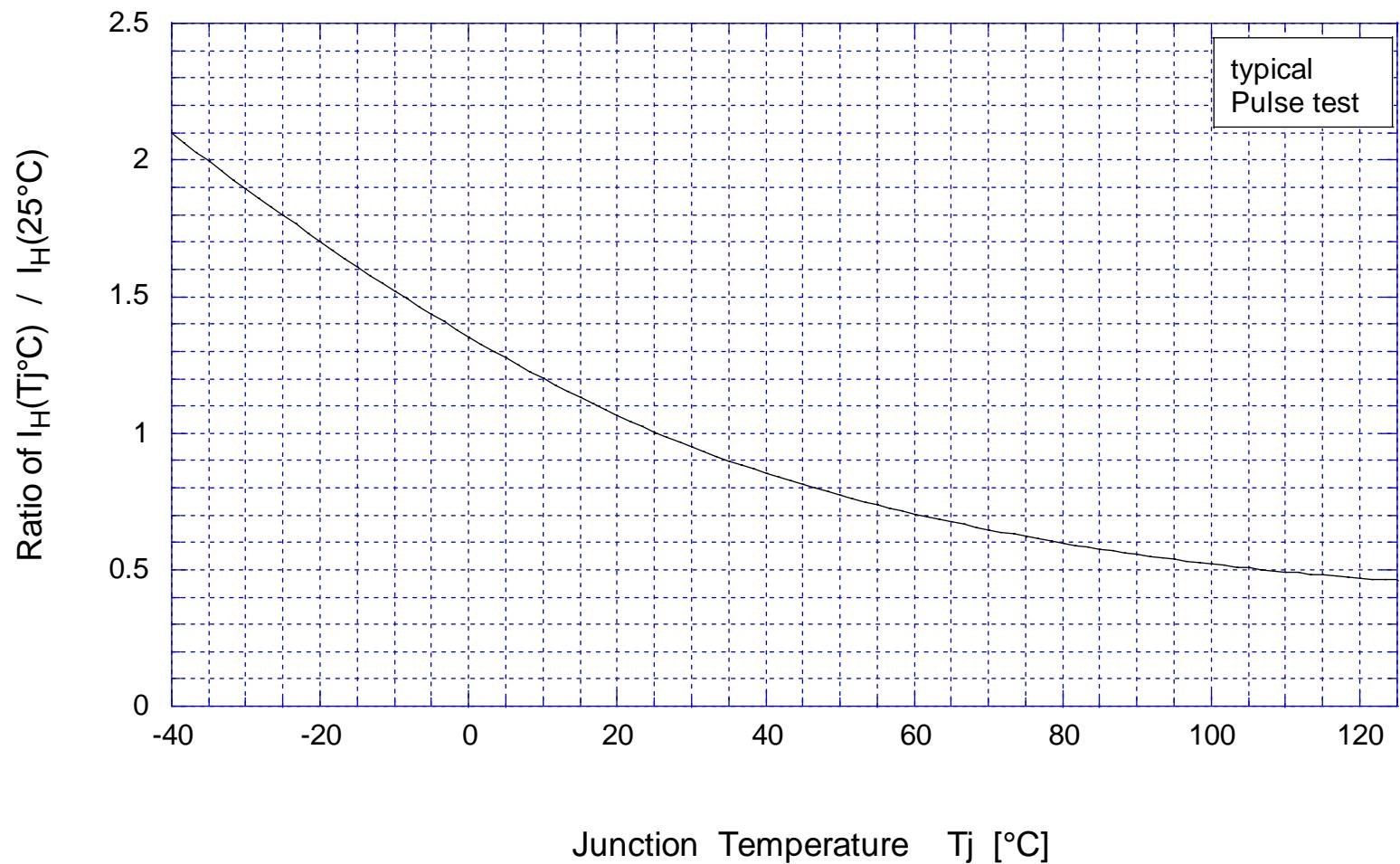
KU10S35N On-State Voltage vs On-State Current



KU10S35N Break Over Voltage vs Junction Temperature

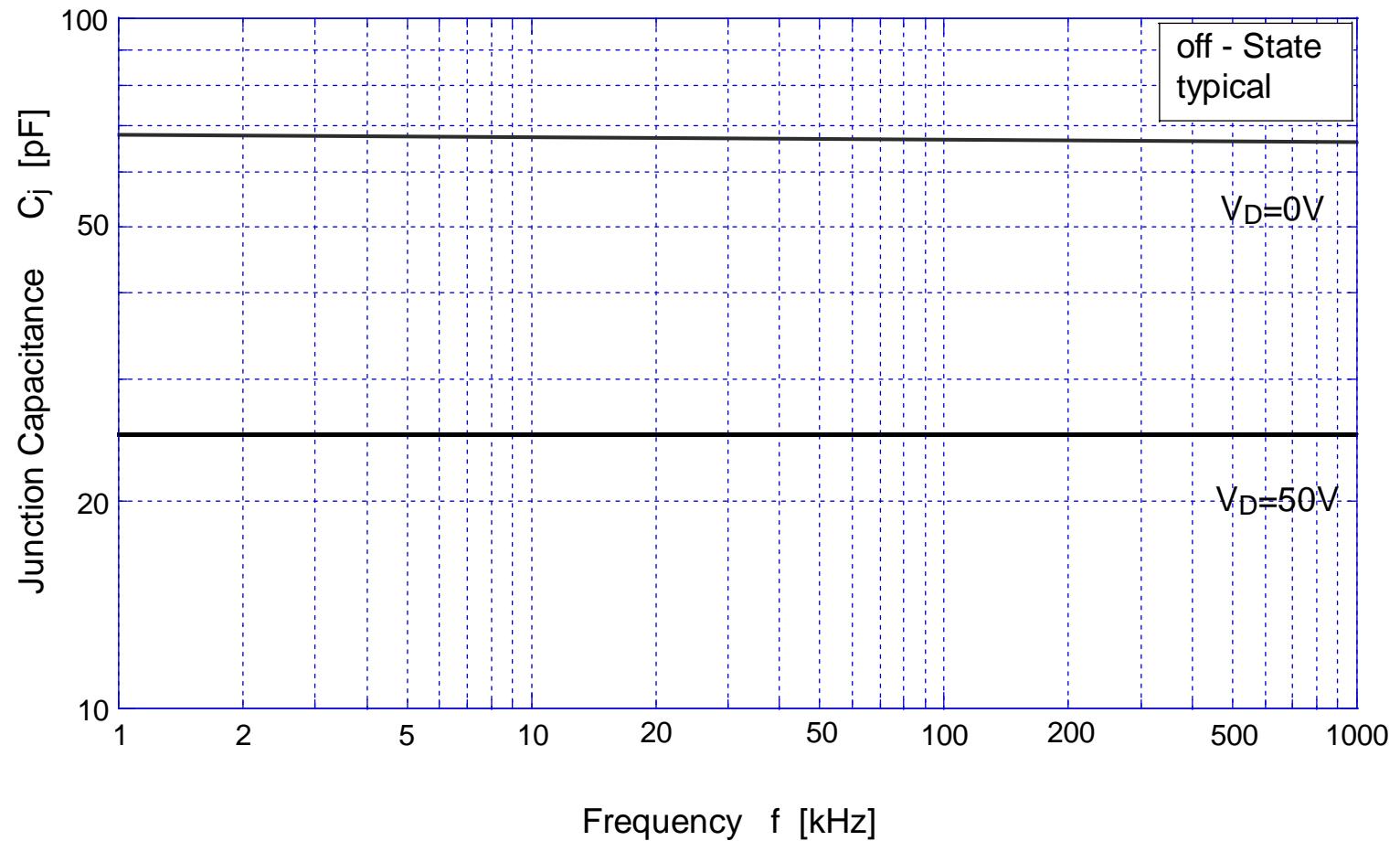


KU10S35N Holding Current vs Junction Temperature



KU10S35N

Junction Capacitance



KU10S35N Junction Capacitance

